

Reflective Object Sensor

OPB700Z, OPB700ALZ

OPB701Z, OPB701ALZ



Features:

- Low profile to facilitate stacking
- Low cost plastic housing
- Choice of phototransistor or photodarlington output
- #26 AWG lead wire in 4" (101 mm), or 18" (457 mm) lengths

Description:

OPB700 and **OPB700ALZ** sensors consist of an infrared emitting diode and a NPN silicon phototransistor, mounted side-by-side on converging optical axes in a black plastic housing.

OPB701 and **OPB701ALZ** sensors consist of an infrared emitting diode and a NPN silicon photodarlington, mounted side-by-side on converging optical axes in a black plastic housing.

The interconnect wires for these devices are UL approved #26 AWG, with Teflon insulation, stripped and tinned. The **OPB700** and **OPB701** have 4" (101 mm) wire length while the **OPB700ALZ** and **OPB701ALZ** have 18" (457 mm) wire length.

Custom electrical, wire, cabling and connectors are available. Contact your local representative or OPTEK for more information.

Applications:

- Non-contact reflective object sensor
- Assembly line automation
- Machine automation
- Machine safety
- End of travel sensor
- Door sensor

Ordering Information				
Part Number	LED Peak Wavelength	Sensor	Reflection Distance Inch (mm)	Lead Length / Spacing
OPB700Z	890 nm	Transistor	0.200" (5.08mm)	4" / 26 AWG Wire
OPB700ALZ				18" / 26 AWG Wire
OPB701Z		Darlington		4" / 26 AWG Wire
OPB701ALZ				18" / 26 AWG Wire



RoHS

General Note

TT Electronics reserves the right to make changes in product specification without notice or liability. All information is subject to TT Electronics' own data and is considered accurate at time of going to print.

TT Electronics | OPTEK Technology
1645 Wallace Drive, Carrollton, TX 75006 | Ph: +1 972 323 2200
www.ttelectronics.com | sensors@ttelectronics.com

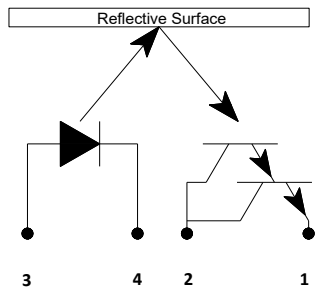
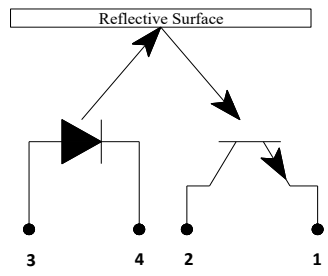
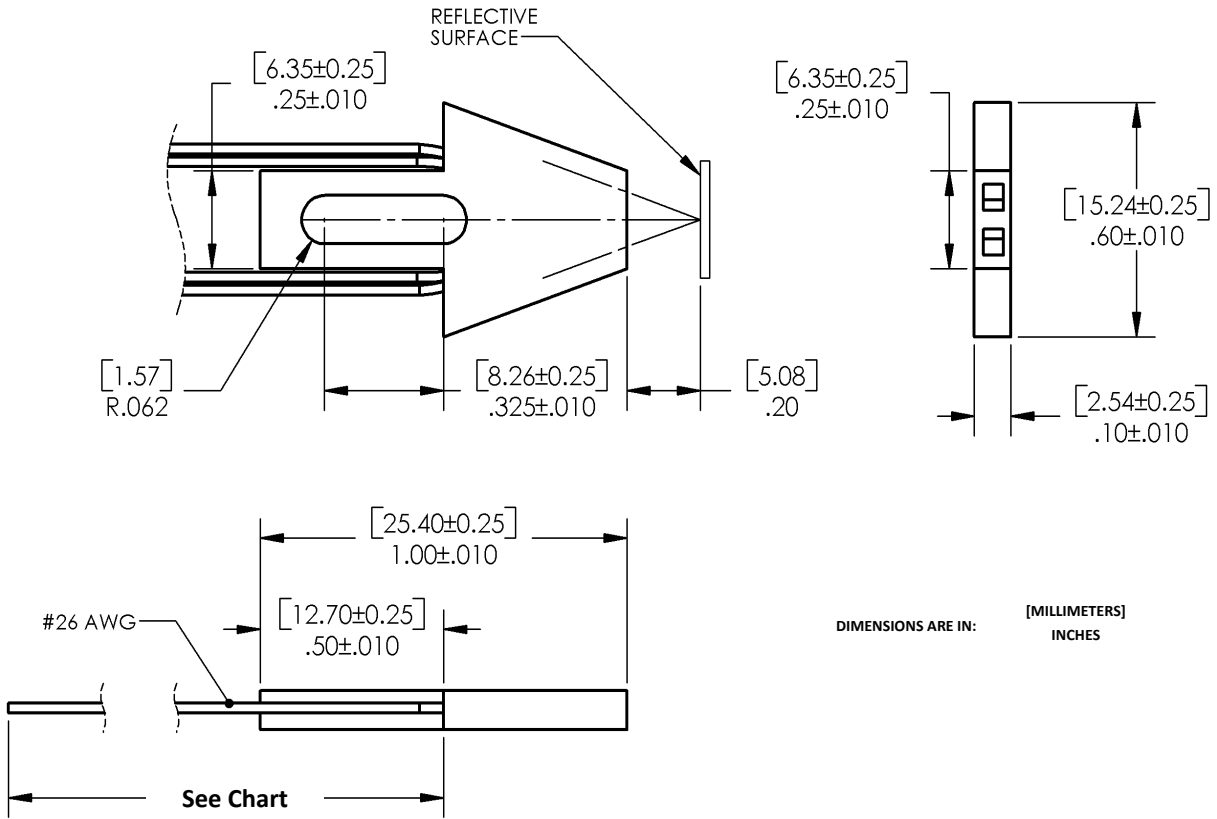
Reflective Object Sensor

OPB700Z, OPB700ALZ

OPB701Z, OPB701ALZ



OPB700Z, OPB701Z



Part Number	Wire Length
OPB700Z	4" Min
OPB700ALZ	18" Min
OPB701Z	4" Min
OPB701ALZ	18" Min

OPB701			
Color/Pin #	LED	Color/Pin #	LED
Red-3	Anode	White-2	Collector
Black-4	Cathode	Green-1	Emitter

General Note
 TT Electronics reserves the right to make changes in product specification without notice or liability. All information is subject to TT Electronics' own data and is considered accurate at time of going to print.

TT Electronics | OPTEK Technology
 1645 Wallace Drive, Carrollton, TX 75006 | Ph: +1 972 323 2200
 www.ttelectronics.com | sensors@ttelectronics.com

Reflective Object Sensor

OPB700Z, OPB700ALZ

OPB701Z, OPB701ALZ



Electrical Specifications

Absolute Maximum Ratings ($T_A = 25^\circ\text{C}$ unless otherwise noted)	
Storage Temperature Range	-40° C to + 125° C
Operating Temperature Range	-40° C to + 100° C
Lead Soldering Temperature	260° C
Input Diode	
Continuous Forward Current	100 mA
Reverse Voltage	2 V
Power Dissipation ⁽¹⁾	80 mW
Output Phototransistor	
Collector-Emitter Voltage OPB700Z, OPB700ALZ OPB701Z, OPB701ALZ	24 V 15 V
Emitter-Collector Voltage	5 V
Power Dissipation ⁽¹⁾	50 mW

Notes:

(1) Derate linearly 1.07 mW/°C above 25 ° C.

Electrical Characteristics ($T_A = 25^\circ\text{C}$ unless otherwise noted)						
SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
Input Diode						
V_F	Forward Voltage	-	-	1.7	V	$I_F = 50\text{ mA}$
I_R	Reverse Current	-	-	100	μA	$V_R = 2\text{ V}$
Output Phototransistor						
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	25	-	-	V	$I_C = 100\ \mu\text{A}$
	OPB700Z, OPB700ALZ OPB701Z, OPB701ALZ	15	-	-	V	$I_C = 100\ \mu\text{A}$
$V_{(BR)ECO}$	Emitter-Collector Breakdown Voltage	5	-	-	V	$I_E = 100\ \mu\text{A}$
I_{CEO}	Collector Dark Current	-	-	100	nA	$V_{CE} = 10\text{ V}, I_F = 0, E_E = \leq 0.1\ \mu\text{W}/\text{cm}^2$
	OPB700Z, OPB700ALZ OPB701Z, OPB701ALZ	-	-	250	nA	$V_{CE} = 10\text{ V}, I_F = 0, E_E = \leq 0.1\ \mu\text{W}/\text{cm}^2$

Notes:

(1) Measured using Eastman Kodak neutral white test card with 90% diffuse reflectance as a reflecting surface. Reference: Eastman Kodak, Catalog # E 152 7795.

General Note

TT Electronics reserves the right to make changes in product specification without notice or liability. All information is subject to TT Electronics' own data and is considered accurate at time of going to print.

TT Electronics | OPTEK Technology
1645 Wallace Drive, Carrollton, TX 75006 | Ph: +1 972 323 2200
www.ttelectronics.com | sensors@ttelectronics.com

Reflective Object Sensor

OPB700Z, OPB700ALZ

OPB701Z, OPB701ALZ



Electrical Specifications

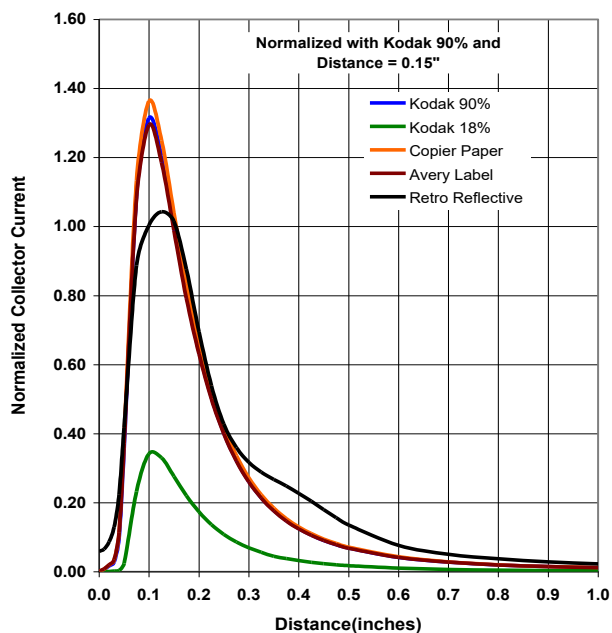
Electrical Characteristics ($T_A = 25^\circ\text{C}$ unless otherwise noted)						
SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
Coupled Parameters OPB700Z, OPB700ALZ (Phototransistor)						
$I_{C(ON)}$	Collector current	0.10	-	2.50	mA	$V_{CE} = 5.0\text{V}^{(1)}$, $I_F = 40\text{mA}$
$V_{CE(SAT)}$	Saturation Voltage	-	-	0.40	V	$I_C = 10\mu\text{A}$, $I_F = 40\text{mA}$
I_{CX}	Leakage Current	-	-	2.00	μA	$V_{CE} = 5.0\text{V}$, $I_F = 40\text{mA}$, NO Reflective Surface
Coupled Parameters OPB701Z, OPB701ALZ (Photodarlington)						
$I_{C(ON)}$	Collector current	2.50	-	43.00	mA	$V_{CE} = 5.0\text{V}^{(1)}$, $I_F = 40\text{mA}$
$V_{CE(SAT)}$	Saturation Voltage	-	-	1.10	V	$I_C = 1.0\text{mA}$, $I_F = 40\text{mA}$
I_{CX}	Leakage Current	-	-	20.0	μA	$V_{CE} = 5.0\text{V}$, $I_F = 40\text{mA}$, NO Reflective Surface

Notes:

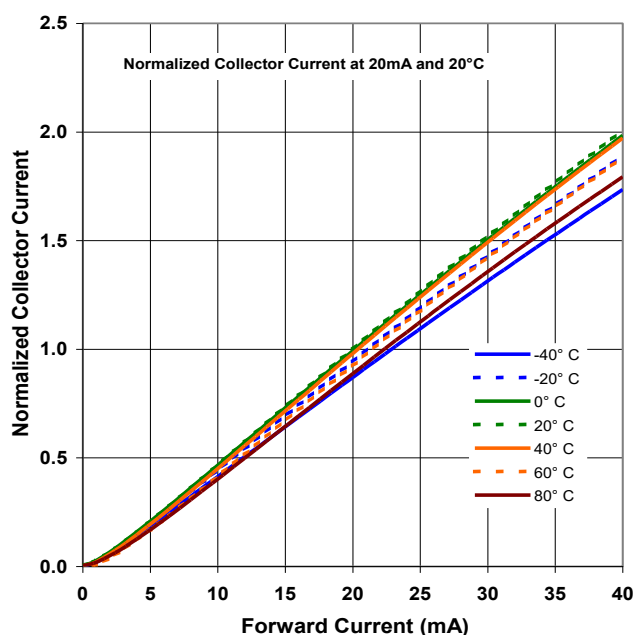
- Measured using Eastman Kodak neutral white test card with 90% diffuse reflectance as a reflecting surface. Reference: Eastman Kodak, Catalog # E 152 7795.

Performance

OPB700 - Normalized Collector Current vs Distance



OPB700 - Normalized Collector Current vs Forward Current vs Temperature



General Note

TT Electronics reserves the right to make changes in product specification without notice or liability. All information is subject to TT Electronics' own data and is considered accurate at time of going to print.

TT Electronics | OPTEK Technology
1645 Wallace Drive, Carrollton, TX 75006 | Ph: +1 972 323 2200
www.ttelectronics.com | sensors@ttelectronics.com

Reflective Object Sensor

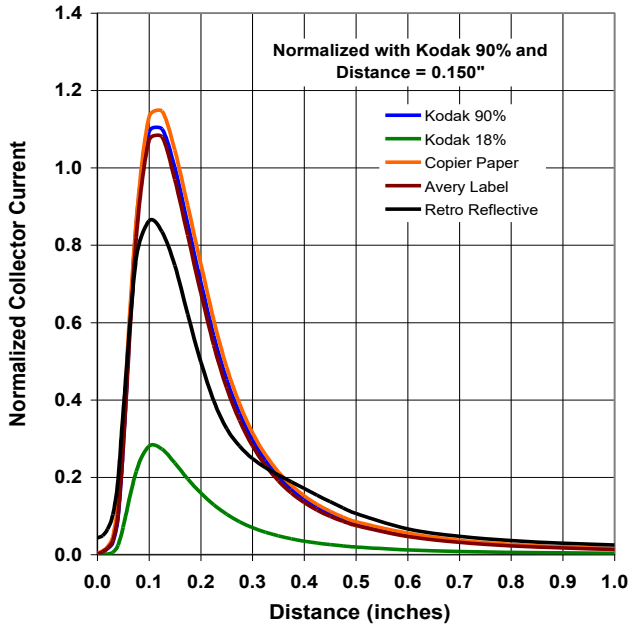
OPB700Z, OPB700ALZ

OPB701Z, OPB701ALZ

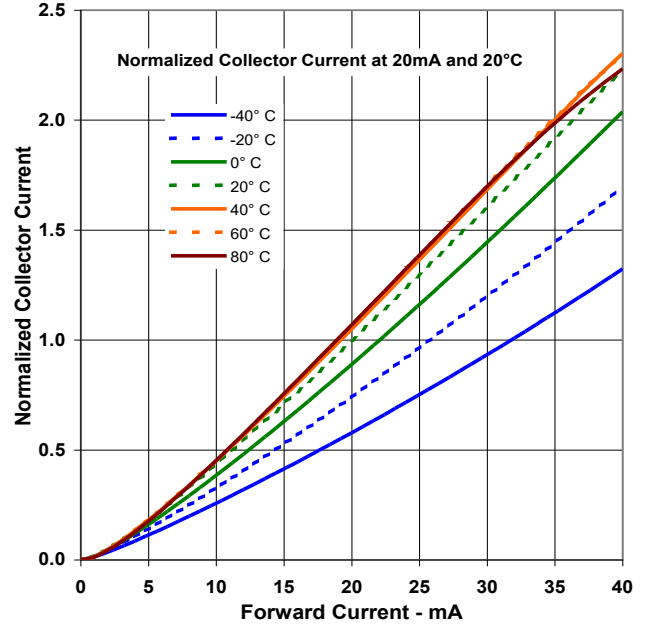


Performance

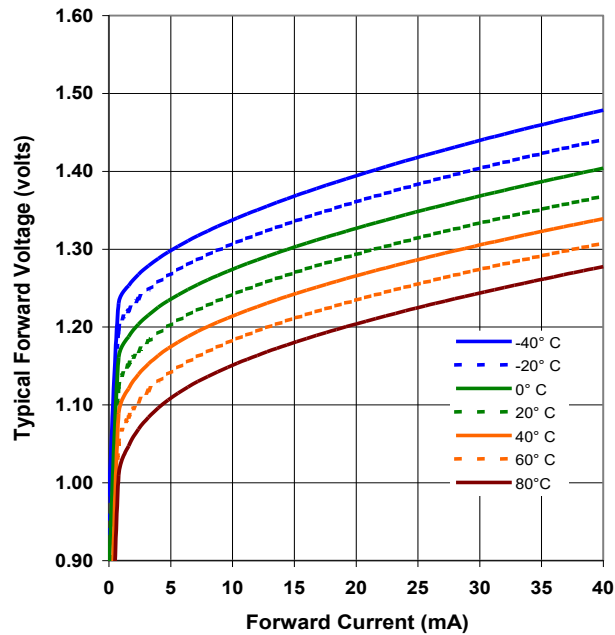
OPB701 - Normalized Collector Current vs Distance



OPB701 - Normalized Collector Current vs Forward Current vs Temperature



LED—Forward Voltage vs Forward Current vs Temperature



General Note

TT Electronics reserves the right to make changes in product specification without notice or liability. All information is subject to TT Electronics' own data and is considered accurate at time of going to print.

TT Electronics | OPTEK Technology
 1645 Wallace Drive, Carrollton, TX 75006 | Ph: +1 972 323 2200
www.ttelectronics.com | sensors@ttelectronics.com

Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9